- InP HEMT Technology
- Lowest Noise Figure
- Wideband LNA, PA

The H2-50 is a 150 um gate width InP HEMT transistor from HRL Laboratories 100 nm H 2 process with a typical cutoff frequency (fT) of 180 GHz . This unpackaged transistor can provide the low noise figure performance for high levels of packaging integration.

Table I Specified Performance at $T_{A}=25^{\circ} \mathrm{C}$

| Parameter | Units | Bias | Min | Typ | Max |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Maximum Transconductance $\left(\mathrm{g}_{\mathrm{m}, \mathrm{max}}\right)$ | ms | $\mathrm{Vds}=1.0 \mathrm{~V}$ | 90 | 120 |  |
| Short Circuit Drain Current $\left(\mathrm{I}_{\mathrm{dss}}\right)$ | mA | $\mathrm{Vds}=1.0 \mathrm{~V}$ <br> $\mathrm{Vgs}=0.0$ | 30 | 45 |  |
| Pinch Off Voltage $\left(\mathrm{V}_{\mathrm{po}}\right)$ | V | $\mathrm{Vds}=1.0 \mathrm{~V}$ | -1 | -0.4 | 0 |
| Gate Leakage $\left(\mathrm{I}_{\mathrm{g}, \mathrm{min}}\right)$ | uA | $\mathrm{Vds}=0.0 \mathrm{~V}$ <br> $\mathrm{Vgs}=-1.0$ |  | 45 | 60 |

Table II Maximum Ratings at $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$

| Symbol | Parameter | Value | Note |
| :---: | :---: | :---: | :---: |
| $V_{D S}$ | Drain to Source Voltage | 2.0 V |  |
| $V_{G D}$ | Gate to Drain Voltage | -3.0 to 0.2 VDC |  |
| $V_{G S}$ | Gate to Source Voltage | -1.0 to 0.2 VDC |  |
| $T_{M}$ | Die Attach Temperature | $290^{\circ} \mathrm{C}$ | 30 Seconds maximum |

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## Typical DC IV Performance at $\mathrm{T}_{A}=25^{\circ} \mathrm{C}$



## Outline Drawing

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